# DM74184/DM74185A BCD-to-Binary and Binary-to-BCD Converters

#### **General Description**

These monolithic converters are derived from the 256-bit read only memories, DM5488, and DM7488. Emitter connections are made to provide direct read-out of converted codes at outputs Y8 through Y1, as shown in the function tables. These converters demonstrate the versatility of a read only memory in that an unlimited number of reference tables or conversion tables may be built into a system. Both of these converters comprehend that the least significant bits (LSB) of the binary and BCD codes are logically equal, and in each case the LSB bypasses the converter as illustrated in the typical applications. This means that a 6-bit converter is produced in each case. Both devices are cascadable to N bits.

An overriding enable input is provided on each converter which when taken high inhibits the function, causing all outputs to go high. For this reason, and to minimize power consumption, unused outputs Y7 and Y8 of the 185A and all "don't care" conditions of the 184 are programmed high. The outputs are of the open-collector type.

#### **DM74184 BCD-TO-BINARY CONVERTERS**

The 6-bit BCD-to-binary function of the DM74184 is analogous to the algorithm:

 a. Shift BCD number right one bit and examine each decade. Subtract three from each 4-bit decade containing a binary value greater than seven.  b. Shift right, examine, and correct after each shift until the least significant decade contains a number smaller than eight and all other converted decades contain zeros.

In addition to BCD-to-binary conversion, the DM74184 is programmed to generate BCD 9's complement or BCD 10's complement. Again, in each case, one bit of the complement code is logically equal to one of the BCD bits; therefore, these complements can be produced on three lines. As outputs Y6, Y7 and Y8 are not required in the BCD-to-binary conversion, they are utilized to provide these complement codes as specified in the function table when the devices are connected as shown.

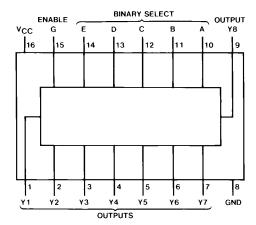
#### **DM74185A BINARY-TO-BCD CONVERTERS**

The function performed by these 6-bit binary-to-BCD converters is analogous to the algorithm:

- Examine the three most significant bits. If the sum is greater than four, add three and shift left one bit.
- b. Examine each BCD decade. If the sum is greater than four, add three and shift left one bit.
- c. Repeat step b until the least-significant binary bit is in the least-significant BCD location.

(Continued)

#### **Connection Diagram**



Order Number DM74184N or DM74185AN See NS Package Number N16E TL/F/6561-1

#### **Absolute Maximum Ratings (Note)**

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage Input Voltage 5.5V Output Voltage 7V Operating Free Air Temperature

Range 0°C to +70°C Storage Temperature Range -65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

## **Recommended Operating Conditions**

Symbol	Parameter	Min	Nom	Max	Units
V <sub>CC</sub>	Supply Voltage	4.75	5	5.25	V
V <sub>IH</sub>	High Level Input Voltage	2			V
V <sub>IL</sub>	Low Level Input Voltage			0.8	V
V <sub>OH</sub>	High Level Output Voltage			5.5	V
l <sub>OL</sub>	Low Level Output Current			12	mA
T <sub>A</sub>	Free Air Operating Temperature	0		70	°C

### '184 and '185A Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	ameter Conditions Min		Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -12 mA$			-1.5	٧
I <sub>CEX</sub>	High Level Output Current	$V_{CC} = Min, V_O = 5.5V$ $V_{IL} = Max, V_{IH} = Min$			100	μΑ
V <sub>OL</sub>	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min, V_{IL} = Max$			0.4	V
II	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$			1	mA
I <sub>IH</sub>	High Level Input Current	$V_{CC} = Max, V_I = 2.4V$			25	μΑ
I <sub>IL</sub>	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$			-1	mA
ICCH	Supply Current with Outputs High	V <sub>CC</sub> = Max		65	95	mA
I <sub>CCL</sub>	Supply Current with Outputs Low	V <sub>CC</sub> = Max		80	99	mA

'184 and '185A Switching Characteristics at  $V_{CC}=5V$  and  $T_A=25^{\circ}C$  (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	From (Input) To (Output)	R <sub>L1</sub> = 400Ω. C <sub>L</sub> = 15 pF (Se	Units	
Oyboi	T di dillotoi	ro (output)	Min	Max	- Cinto
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	Enable G to Output		35	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	Enable G to Output		35	ns
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	Binary Select to Output		35	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	Binary Select to Output		35	ns

Note 1: All typicals are at  $V_{CC}=5V$ ,  $T_A=25^{\circ}C$ .

# **General Description** (Continued)

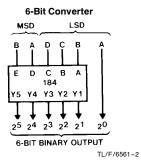
#### DM74184 BCD-to-Binary

TABLE I. Package Count and Delay Times for BCD-to-Binary Conversion

· · · · · · · · · · · · · · · · · · ·									
Input	Packages	Total Delay Times (ns)							
(Decades)	Required	Тур	Max						
2	2	56	80						
3	6	140	200						
4	12	196	280						
5	19	280	400						
6	28	364	520						

BCD 9's

**Complement Converter** 



BCD
D C B A
184
Y8 Y7 Y6
ND NC NB NA

Complement Converter

BCD

5V D C B A

E D C B A

184

Y8 Y7 Y6

BCD 10'S COMPLEMENT

BCD's 10's

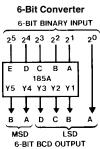
BCD 9'S COMPLEMENT

DM74185A Binary-to-BCD

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TABLE II. Package Count and Delay Times for Binary-to-BCD Conversion

Input	Packages	Total Delay	Times (ns)
(Bits)	Required	Тур	Max
4 to 6	1	25	40
7 or 8	3	50	80
9	4	75	120
10	6	100	160
11	7	125	200
12	8	125	200
13	10	150	240
14	12	175	280
15	14	175	280
16	16	200	320
17	19	225	360
18	21	225	360
19	24	250	400
20	27	275	440



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TL/F/6561-4

Rin	arv			I	nputs			Outputs							
	rds		Bin	ary Sel	ect		Enable								
		E	D	C	В	Α	G	Y8	<b>Y7</b>	Y6	Y5	Y4	Y3	Y2	Y1
0	1	L	L	L	L	L	L	Н	Н	L	L	L	L	L	L
2	3	L	L	L	L	Н	L	Н	Н	L	L	L	L	L	Н
4	5	L	L	L	Н	L	L	Н	Н	L	L	L	L	Н	L
6	7	L	L	L	Н	Н	L	Н	Н	L	L	L	L	Н	Н
8	9	L	L	Н	L	L	L	Н	Н	L	L	L	Н	L	L
10	11	L	L	Н	L	Н	L	Н	Н	L	L	Н	L	L	L
12	13	L	L	Н	Н	L	L	Н	Н	L	L	Н	L	L	Н
14	15	L	L	Н	Н	Н	L	Н	Н	L	L	Н	L	Н	L
16	17	L	Н	L	L	L	L	Н	Н	L	L	Н	L	Н	Н
18	19	L	Н	L	L	Н	L	Н	Н	L	L	Н	Н	L	L
20	21	L	Н	L	Н	L	L	Н	Н	L	Н	L	L	L	L
22	23	L	Н	L	Н	Н	L	Н	Н	L	Н	L	L	L	Н
24	25	L	Н	Н	L	L	L	Н	Н	L	Н	L	L	Н	L
26	27	L	Н	Н	L	Н	L	Н	Н	L	Н	L	L	Н	Н
28	29	L	Н	Н	Н	L	L	Н	Н	L	Н	L	Н	L	L
30	31	L	Н	Н	Н	Н	L	Н	Н	L	Н	Н	L	L	L
32	33	Н	L	L	L	L	L	Н	Н	L	Н	Н	L	L	Н
34	35	н	L	L	L	Н	L	Н	Н	L	Н	Н	L	Н	L
36	37	Н	L	L	Н	L	L	Н	Н	L	Н	Н	L	Н	Н
38	39	Н	L	L	Н	Н	L	Н	Н	L	Н	Н	Н	L	L
40	41	Н	L	Н	L	L	L	Н	Н	Н	L	L	L	L	L
42	43	Н	L	Н	L	Н	L	Н	Н	Н	L	L	L	L	Н
44	45	Н	L	Н	Н	L	L	Н	Н	Н	L	L	L	Н	L
46	47	Н	L	Н	Н	Н	L	Н	Н	Н	L	L	L	Н	Н
48	49	Н	Н	L	L	L	L	Н	Н	Н	L	L	Н	L	L
50	51	Н	Н	L	L	Н	L	Н	Н	Н	L	Н	L	L	L
52	53	Н	Н	L	Н	L	L	Н	Н	Н	L	Н	L	L	Н
54	55	Н	Н	L	Н	Н	L	Н	Н	Н	L	Н	L	Н	L
56	57	Н	Н	Н	L	L	L	Н	Н	Н	L	Н	L	Н	Н
58	59	Н	Н	Н	L	Н	L	Н	Н	Н	Ĺ	Н	H	L	L
60	61	Н	Н	Н	Н	L	L	Н	Н	Н	Н	L	L	L	L
62	63	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	L	L	L	Н
^	VII	Х	Х	X	Х	X	Н	Н	Н	Н	Н	Н	Н	Н	Н

### Function Tables (Continued)

**BCD-to-Binary Converter** 

BCD Words			Inputs (See Note A)						Outputs (See Note B)				
		E	D	С	В	Α	G	<b>Y</b> 5	<b>Y</b> 4	<b>Y</b> 3	<b>Y2</b>	<b>Y</b> 1	
0	1	L	L	L	L	L	L	L	L	L	L	L	
2	3	L	L	L	L	Н	L	L	L	L	L	Н	
4	5	L	L	L	Н	L	L	L	L	L	Н	L	
6	7	L	L	L	Н	Н	L	L	L	L	Н	Н	
8	9	L	L	Н	L	L	L	L	L	Н	L	L	
10	11	L	Н	L	L	L	L	L	L	Н	L	Н	
12	13	L	Н	L	L	Н	L	L	L	Н	Н	L	
14	15	L	Н	L	Н	L	L	L	L	Н	Н	Н	
16	17	L	Н	L	Н	Н	L	L	Н	L	L	L	
18	19	L	Н	Н	L	L	L	┙	Н	L	L	Н	
20	21	Н	L	L	L	L	L	L	Н	L	Н	L	
22	23	Н	L	L	L	Н	L	L	Н	L	Н	Н	
24	25	Н	L	L	Н	L	L	L	Н	Н	L	L	
26	27	Н	L	L	Н	Н	L	L	Н	Н	L	Н	
28	29	Н	L	Н	L	L	L	L	Н	Н	Н	L	
30	31	Н	Н	L	L	L	L	L	Н	Н	Н	Н	
32	33	Н	Н	L	L	Н	L	Н	L	L	L	L	
34	35	Н	Н	L	Н	L	L	Н	L	L	L	Н	
36	37	Н	Н	L	Н	Н	L	Н	L	L	Н	L	
38	39	Н	Н	Н	L	L	L	Н	L	L	Н	Н	
ıΑ	ny	Х	Χ	Χ	Χ	Χ	Н	Η	Н	Н	Н	Н	

BCD 9's or BCD 10's Complement Converter

BCD Word		(S	Inpi ee N	Outputs (See Note D)					
Word	Ε†	D	С	В	Α	G	Y8	<b>Y7</b>	<b>Y</b> 6
0	L	L	L	L	L	L	Н	L	Н
1	L	L	L	L	Н	L	Н	L	L
2	L	L	L	Н	L	L	L	Н	Н
3	L	L	L	Н	Н	L	L	Н	L
4	L	L	Н	L	L	L	L	Н	Н
5	L	L	Н	L	Н	L	L	Н	L
6	L	L	Н	Н	L	L	L	L	Н
7	L	L	Н	Н	Н	L	L	L	L
8	L	Н	L	L	L	L	L	L	Н
9	L	Н	L	L	Н	L	L	L	L
0	Н	L	L	L	L	L	L	L	L
1	Н	L	L	L	Н	L	Н	L	L
2	Н	L	L	Н	L	L	Н	L	L
3	Н	L	L	Н	Н	L	L	Н	Н
4	Н	L	Н	L	L	L	L	Н	Н
5	Н	L	Н	L	Н	L	L	Н	L
6	Н	L	Н	Н	L	L	L	Н	L
7	Н	L	Н	Н	Н	L	L	L	Н
8	Н	Н	L	L	L	L	L	L	Н
9	Н	Н	L	L	Н	L	┙	L	L
Any	Х	Х	Χ	Χ	Χ	Н	Н	Н	Н

Note A: Input Conditions other than those shown produce highs at outputs Y1 through Y5.

Note B: Output Y6, Y7, and Y8 are not used for BCD-to-Binary conversion.

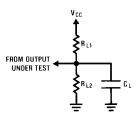
Note C: Input conditions other than those shown produce highs at outputs Y6, Y7, and Y8.

Note D: Outputs Y1 through Y5 are not used for BCD 9's or BCD 10's complement conversion.

†When these devices are used as complement converters, input E is used as a mode control. With this input low, the BCD 9's complement is generated; when it is high, the BCD 10's complement is generated.

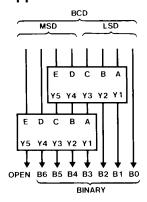
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### **Test Circuit**



C<sub>L</sub> includes probe and jig capacitance

### **Typical Applications**

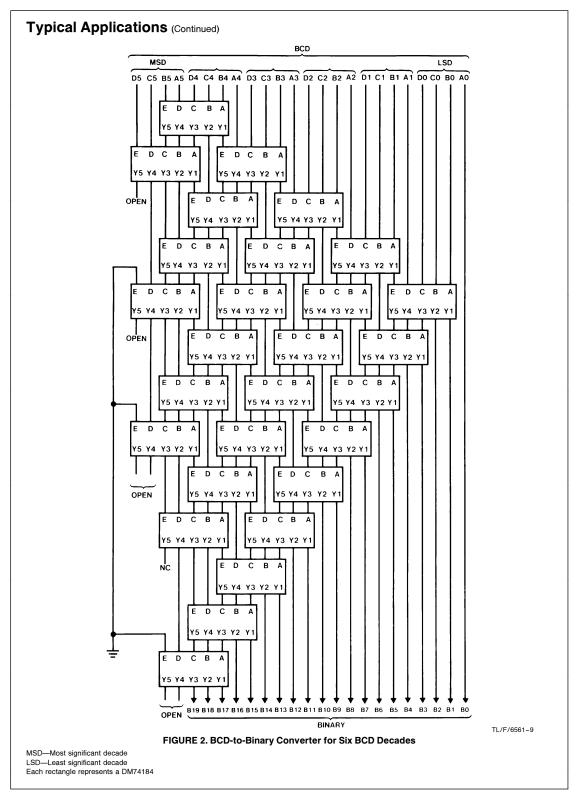


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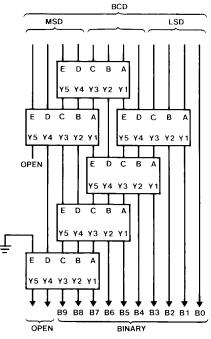
FIGURE 1. BCD-to-Binary Converter for Two BCD Decades

MSD—Most significant decade LSD—Least significant decade Each rectangle represents a DM74184

H = High Level, L = Low Level, X = Don't Care



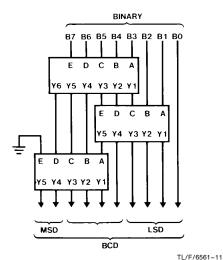
## Typical Applications (Continued)



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# FIGURE 3. BCD-to-Binary Converter for Three BCD Decades

MSD—Most significant decade LSD—Least significant decade Each rectangle represents a DM74184



#### FIGURE 5. 8-Bit Binary-to-BCD Converter

MSD—Most significant decade LSD—Least significant decade

**Note A:** Each rectangle represents a DM74185A. **Note B:** All unused E inputs are grounded.

BINARY

B5 B4 B3 B2 B1 B0

E D C B A

Y6 Y5 Y4 Y3 Y2 Y1

MSD LSD

BCD

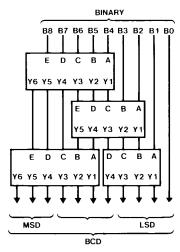
#### FIGURE 4. 6-Bit Binary-to-BCD Converter

TI /F/6561-10

MSD—Most significant decade LSD—Least significant decade

Note A: Each rectangle represents a DM74185A.

Note B: All unused E inputs are grounded.



# TL/F/6561-12 FIGURE 6. 9-Bit Binary-to-BCD Converter

MSD—Most significant decade LSD—Least significant decade

Note A: Each rectangle represents a DM74185A.

Note B: All unused E inputs are grounded.

# **Typical Applications** (Continued)

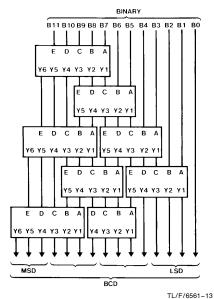


FIGURE 7. 12-Bit Binary-to-BCD Converter (See Note B)

MSD—Most significant decade LSD—Least significant decade

Note A: Each rectangle represents a DM74185A.

Note B: All unused E inputs are grounded.

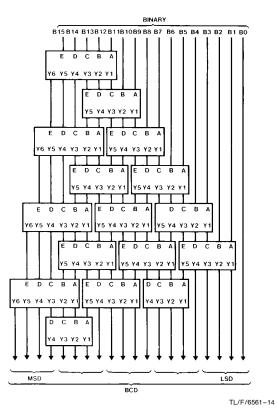
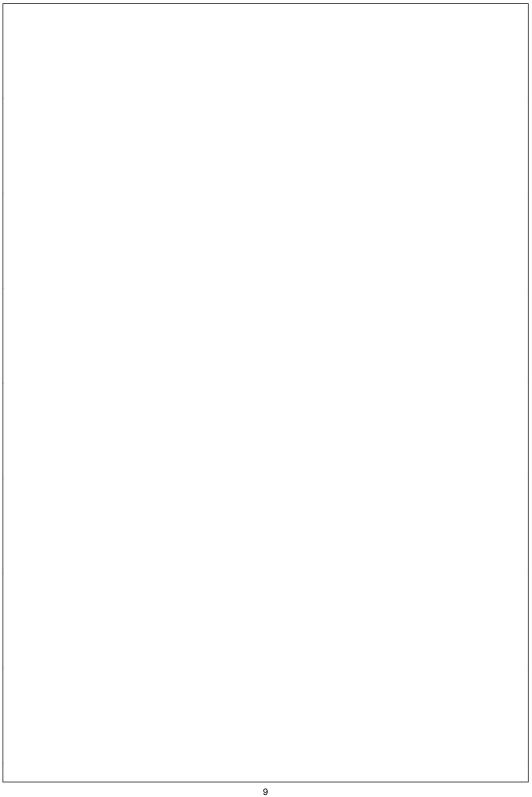
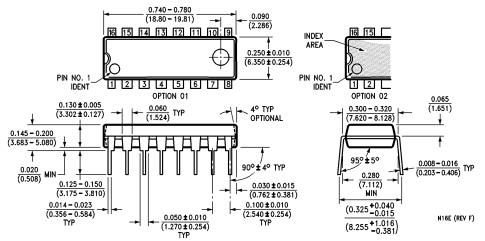


FIGURE 8. 16-Bit Binary-to-BCD Converter (See Note B)



### Physical Dimensions inches (millimeters)



16-Lead Molded Dual-In-Line Package (N) Order Number DM74184N or DM74185AN NS Package Number N16E

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